HD14006B

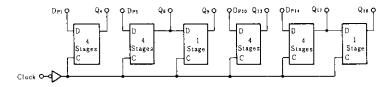
18-bit Static Shift Register

The HD14006B shift register is comprised of four separate shift register sections sharing a common clock: two sections have four stages and two sections have five stages with an output tap on both the fourth and fifth stages. This makes it possible to obtain a shift register of 4, 5, 8, 9, 10, 12, 13, 14, 16, 17 or 18 bits by appropriate selection of inputs and outputs. This part is particularly useful in serial shift registers and time delay circuits.

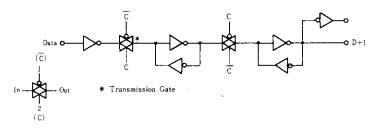
■ FEATURES

- Output Transitions Occur on the Falling Edge of the Clock Pulse
- Quiescent Current = 5nA/pkg typ @5V
- Fully Static Operation
- 8MHz Shift Rate Typical
- Can be Cascaded to Provide Longer Shift Register Lengths
- Supply Voltage Range = 3 to 18V
- Capable of Driving One Lowpower Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Replacement for CD4006B and MC14006B

■ BLOCK DIAGRAM

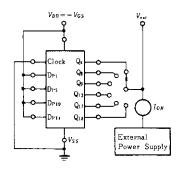


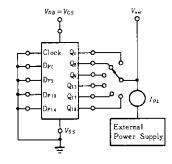
■LOGIC DIAGRAM



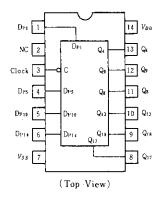
■DC CHARACTERISTIC TEST CIRCUIT

● 1_{0H}





■ PIN ARRANGEMENT



TRUTH TABLE

D _n	С	Q_{n+1}
0		0
1 .		1
×		Q,

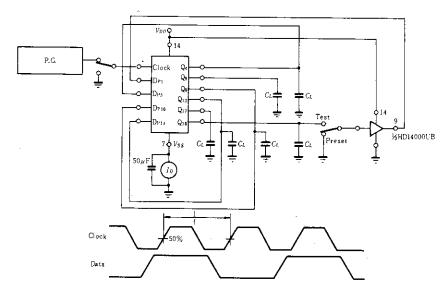
X: Don't Care

■ ELECTRICAL CHARACTERISTICS

Characteristic Syml	Symbol		Test Conditions	4	40 ℃		25 ℃			85℃		
Characteristic	Symbol	$V_{DD}(V)$	lest Conditions	min	max	min	typ	max	min	max	v Uni	
1	<u> </u>	5.0	Via=VDD or 0	_	0.05		0	0.05	_	0.05	v	
	Vol	10		_	0.05	_	0	0.05	-	0.05		
Output Voltage		15		_	0.05	-	0	0.05	_	0.05		
Output Voltage		5.0	$V_{ix}=0$ or V_{DD}	4.95	_	4.95	5.0	_	4.95	_	v	
	V _{OH}	10		9.95	-	9.95	10		9.95	-		
		15		14.95		14.95	15		14.95			
14		5.0	$V_{out}=4.5$ or $0.5\mathrm{V}$		1.5	_	2.25	1.5	_	1.5	4	
	VIL	10	$V_{out} = 9.0 \text{ or } 1.0 \text{V}$		3.0	_	4.50	3.0	_	3.0		
Input Voltage		15	$V_{\rm out} = 13.5 \text{ or } 1.5 \text{V}$		4.0	_	6.75	4.0	-	4.0		
Impor Voltage	5.0	V _{rut} =0.5 or 4.5V	3.5	_	3.5	2.75	-	3.5				
	V_{tB}	10	V _{out} =1.0 or 9.0V	7.0		7.0	5.50	-	7.0		v	
		15	$V_{\text{out}} = 1.5 \text{ or } 13.5 \text{V}$	11.0		11.0	8.25		11.0		1	
Output Drive Current	Іон	5.0	$V_{OH}=2.5\mathrm{V}$	-1.0	-	-0.8	-1.7	_	-0.6		mA	
		5.0	$V_{OH}=4.6V$	-0.2	_	-0.16	-0.36		-0.12	_		
		10	$V_{0H} = 9.5 \text{V}$	-0.5	_	-0.4	0.9		-0.3			
		15	$V_{OH} = 13.5 \text{V}$	-1.4	_	-1.2	-3.5		-1.0	_	İ	
	IoL	5.0	$V_{OL}=0.4V$	0.52	_	0.44	0.88	_	0.36		mA	
		10	$V_{OL}=0.5V$	1.3		1.1	2.25		0.9	_		
		15	$V_{OL} = 1.5 \text{V}$	3.6	_	3.0	8.8		2.4			
Input Current	I_{in}	15		_	±0.3	_	±0.00001	±0.3		±1.0	μA	
Input Capacitance	Cin	<u> </u>	$V_{in} = 0$		_	_	5.0	7.5	_		pF	
Quiescent Current IDD		5.0	Zero Signal,	_	20	_	0.005	20	_	150	μΑ	
	IDD	10			40	_	0,010	40		300		
		15	per Package		80	_	0.015	80	-	600		
		5.0	Dynamic $\div I_{DD}$,	T -	_	_	1.3		_			
Total Supply Current*	I_{T}	10	Per Gate,	_	_	_	2.6				μA	
		15	$C_L = 50 \text{pF}, f = 1 \text{kHz}$		_		3.9				/	

^{*} To calculate total supply current at frequency other than 1kHz. $@V_{DB} = 5.0V$ $I_7 = (1.3 \mu A/kHz)f + I_{DB}$, $@V_{DB} = 10V$ $I_7 = (2.6 \mu A/kHz)f + I_{DB}$, $@V_{DB} = 15V$ $I_7 = (3.9 \mu A/kHz)f + I_{DB}$

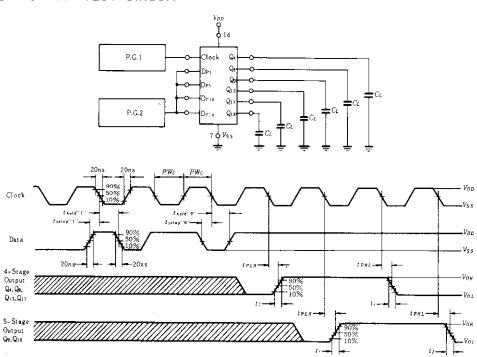
■POWER DISSIPATION TEST CIRCUIT AND WAVEFORM



SWITCHING CHARACTERISTICS ($C_L = 50 \,\mathrm{pF}$, $Ta = 25 \,^{\circ}\mathrm{C}$)

Characteristic	Symbol	$V_{DD}(V)$	min	typ	max	Unit
		5.0	-	180	400	ns
Output Rise Time		10	_	90	200	
		15	_	65	160	
		5.0	_	100	200	ns
Output Fall Time	t_f	10	_	50	100	
		15	-	37	80	
	t _{PLH} ,	5.0	_	305	600	ns
Propagation Delay Time	t _{PHL}	10	_	110	275	
	T P H L	15		80	200	
	PW_{c}	5.0	250	100		ns
Clock Pulse Width		10	125	60		
		15	95	40		
		5.0		5.0	2.0	MHz
Clock Pulse Frequency	PRF	10		8.3	4.0	
		15	_	12	6.0	
		5.0			15	μѕ
Clock Pulse Rise and Fall Time	t_{+}, t_{f}	10	_	_	15	
		15	_	_	15	
		5.0	0	-50	_	ns
Setup Time	tsecup	10	0	-15	_	
		15	0	-8.0		
·		5.0	220	75	_	
Hold Time	$t_{\it hatd}$	10	110	25	_	ns
		15	90	20	_	

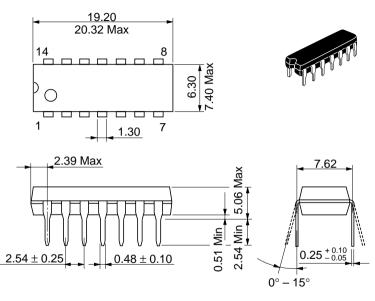
■ SWITCHING TIME TEST CIRCUIT



Output state can change since data previously clocked in might be in either state.



Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

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